

# Description

The SFA0002 is the switching power supply IC for flyback circuit and has high accuracy error amplifier.

When the load of the power supply circuit becomes light, the operation of IC becomes the burst oscillation mode in order to improve the circuit efficiency.

By employing the primary-side regulation, the IC realizes low component counts and design-friendliness, leading to downsizing and standardization of the power supply circuit.

# Features

- AEC-Q100 Qualified
- Current Mode Type PWM Control (Switching frequency can be adjusted by external capacitor)
- Reducing External Component Count by Primary-side Regulation
- Built-in High Accuracy Error Amplifier ( $V_{FB} = 2.5 \text{ V} \pm 2\%, -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$ )
- Operation Mode Normal Operation: PWM Mode Light Load Operation: Burst Oscillation
- Soft Start Function (Startup time can be adjusted by external capacitor)
- Drive Output Stop Function

• Protections: Overcurrent Protection (OCP): Pulse-by-Pulse Overload Protection (OLP): Auto-restart Thermal Shutdown Protection (TSD) with Hysteresis: Auto-restart

# **Typical Application**



# **Specifications**

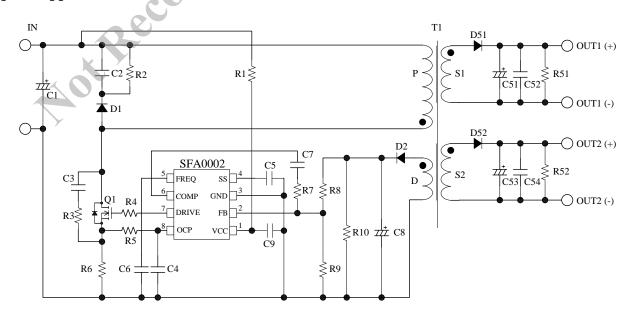
Package

SOP8

- Maximum Power Supply Voltage, V<sub>CC</sub> 36 V
- Adjustable Switching Frequency (20 kHz to 200 kHz)

# Applications

- For following Isolation auxiliary power supply:
- Inverter
- On-board Charger (OBC)
- Battery Management System (BMS)



# Contents

Description1
Contents2
1. Absolute Maximum Ratings3
2. Recommended Operating Conditions3
3. Electrical Characteristics3
4. Performance Curves 5
5. Block Diagram6
6. Pin Configuration and Definitions6
7. Typical Application7
8. Physical Dimensions8
<ul> <li>9. Marking Diagram8</li> </ul>
10 Timing Chart
11. Operational Description 11
11. Operational Description
11.1.1. VCC
11.1.2. FB 11 11.1.3. GND
11.1.4. SS 11
11.1.5. FREO 11
11.1.6. COMP 11
11.1.0. COMI
11.1.7. DRV 11
11.1.7. DRV
11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12
11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12
11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12         11.5. Burst Function in Light Load       13
11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12         11.5. Burst Function in Light Load       13         11.6. Oscillation Frequency Setting       13
11.1.7. DRV       11         11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12         11.5. Burst Function in Light Load       13         11.6. Oscillation Frequency Setting       13         11.7. Drive Stop Function       14
11.1.7. DRV       11         11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12         11.5. Burst Function in Light Load       13         11.6. Oscillation Frequency Setting       13         11.7. Drive Stop Function       14         11.8. Overcurrent Protection (OCP)       14
11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12         11.5. Burst Function in Light Load       13         11.6. Oscillation Frequency Setting       13         11.7. Drive Stop Function       14         11.8. Overcurrent Protection (OCP)       14         11.9. Overload Protection (OLP)       15
11.1.7. DRV       11         11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12         11.5. Burst Function in Light Load       13         11.6. Oscillation Frequency Setting       13         11.7. Drive Stop Function       14         11.8. Overcurrent Protection (OCP)       14
11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12         11.5. Burst Function in Light Load       13         11.6. Oscillation Frequency Setting       13         11.7. Drive Stop Function       14         11.8. Overcurrent Protection (OCP)       14         11.9. Overload Protection (OLP)       15
11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12         11.5. Burst Function in Light Load       13         11.6. Oscillation Frequency Setting       13         11.7. Drive Stop Function       14         11.8. Overcurrent Protection (OCP)       14         11.9. Overload Protection (OLP)       15         11.10. Thermal Shutdown (TSD)       15
11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12         11.5. Burst Function in Light Load       13         11.6. Oscillation Frequency Setting       13         11.7. Drive Stop Function       14         11.8. Overcurrent Protection (OCP)       14         11.9. Overload Protection (OLP)       15         11.10. Thermal Shutdown (TSD)       15
11.1.7. DRV       11         11.1.8. OCP       11         11.2. IC Startup       12         11.3. Soft Start Function       12         11.4. Constant Voltage Control       12         11.5. Burst Function in Light Load       13         11.6. Oscillation Frequency Setting       13         11.7. Drive Stop Function       14         11.8. Overcurrent Protection (OCP)       14         11.9. Overload Protection (OLP)       15         11.10. Thermal Shutdown (TSD)       15

#### 1. **Absolute Maximum Ratings**

Current polarities are defined as follows: current going into the IC (sinking) is positive current (+); current coming out of the IC (sourcing) is negative current (-). Unless otherwise specified.  $T_{A} = 25 \ ^{\circ}C$ 

Parameter	Symbol	Conditions	Rating	Unit	Remarks		
OCP Pin Voltage	V <sub>OCP</sub>		-5 to 5	V			
SS Pin Voltage	V <sub>SS</sub>		-0.3 to 9	V			
FB Pin Voltage	V <sub>FB</sub>		-0.3 to 5	V			
VCC Pin Voltage	V <sub>CC</sub>		0 to 36	V			
COMP Pin Voltage	V <sub>COMP</sub>		-0.3 to 5	V	5		
FREQ Pin Voltage	V <sub>FREQ</sub>		-0.3 to 5	V			
DRIVE Pin Peak Current	I <sub>DRV(PEAK)</sub>		-270 to 540	mA	0		
DRIVE Pin DC Current	I <sub>DRV(DC)</sub>		-90 to 180	mA			
Power Dissipation	P <sub>D</sub>	* Mounting on PCB	1.2	W			
Junction Temperature	T <sub>J</sub>		-40 to 150	°C			
Storage Temperature	T <sub>stg</sub>		-40 to 150	°C			
* PCB: 42 mm × 32 mm in siz	e, 1 mm in thick	kness					
2. Recommended Operating Conditions							

#### **Recommended Operating Conditions** 2.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	Remarks
VCC Pin Voltage	V <sub>CC</sub>		6		24	V	
Switching Frequency	f <sub>OSC</sub>		20	_	200	kHz	

#### **Electrical Characteristics** 3.

Current polarities are defined as follows: current going into the IC (sinking) is positive current (+); current coming out of the IC (sourcing) is negative current (-).

Unless otherwise specified,  $T_A = -40$  °C to 125 °C, VCC = 14 V, and FB = SS = OCP = 0 V.

The following electrical characteristics in  $T_A = -40$  °C to 125 °C are guaranteed by design. The shipping test temperature of the products is -30 °C, 25 °C, and 125 °C.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	Remarks	
Power Supply Startup Operation								
Operation Start Voltage	V <sub>CC(ON)</sub>		4.9	5.1	5.3	V		
Operation Stop Voltage	V <sub>CC(OFF)</sub>		4.4	4.6	4.8	V		
Circuit Current in Operation	I <sub>CC(ON)</sub>		1.0	2.0	3.2	mA		
Circuit Current in Non-operation	I <sub>CC(OFF)</sub>	VCC = 4.8 V	0.3	0.5	1.0	mA		
Normal Operation								
SS Pin High Threshold Voltage of OLP Operation	V <sub>HSS</sub>		1.9	2.0	2.1	V		
SS Pin Low Threshold Voltage of OLP Operation	V <sub>LSS</sub>		0.9	1.0	1.1	V		

# SFA0002

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Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	Remarks
SS Pin Voltage Hysteresis of OLP Operation	$\Delta V_{SS}$	$V_{\rm HSS} - V_{\rm LSS}$	0.9	1.0	1.1	V	
SS Pin Source Current	I <sub>SRC(SS)</sub>	SS = 0.9 V	-19	-15	-11	μΑ	
SS Pin Sink Current	I <sub>SNK(SS)</sub>	SS = 2.1 V	13	17	21	μΑ	
Switching Frequency	f <sub>OSC(200p)</sub>	$FREQ = 200 \ pF$	85	100	115	kHz	
FREQ Pin Source Current	I <sub>SRC(FREQ)</sub>	FREQ = 0.9 V	-33	-30	-27	μΑ	
FREQ Pin Sink Current	I <sub>SNK(FREQ)</sub>	FREQ = 2.1 V	75	85	95	μA	
Oscillation Circuit High Threshold Voltage	$V_{\rm HF}$		1.9	2.0	2.1	v	S
Oscillation Circuit Low Threshold Voltage	$V_{LF}$		0.9	1.0	1.1	v	
Maximum Duty Cycle	D <sub>MAX</sub>	FREQ = 200pF	70	74	78	%	
Slope Compensation Rate	SLP		2.1	2.5	2.9	mV/%	
Feedback Voltage	$V_{FB}$		2.45	2.50	2.55	V	
Burst Operation Threshold Voltage	V <sub>BURST</sub>	FREQ = 200pF, COMP pin voltage increases from 0 V.		0.18		v	
Drive Voltage	V <sub>DRIVE</sub>	FREQ = 3 V, 1 pulse	7.6	8.3	9.0	v	
Minimum Drive Voltage	V <sub>DRIVE(MIN)</sub>	$VCC \ge 6 V,$ FREQ = 3 V, 1 pulse	4	_	—	V	
Minimum On-time	t <sub>ON(MIN)</sub>	OCP = 1 V, DRIVE = 680 pF		170		ns	
<b>Protection Function</b>							
Leading Edge Blanking Time*	t <sub>BW</sub>	C	_	100		ns	
OCP Threshold Voltage	V <sub>OCP</sub>		0.46	0.50	0.54	v	
OLP Delay Time	t <sub>OLP</sub>	SS = 10  nF	32	42	52	ms	
Drive Stop Threshold Voltage	V <sub>ST</sub>		3.5	4.0	4.5	V	
Thermal Shutdown Operating Temperature*	T <sub>JH(TSD)</sub>		150	165		°C	
Thermal Shutdown Release Temperature*	T <sub>JL(TSD)</sub>			150		°C	

\* Guaranteed by design.

# 4. Performance Curves

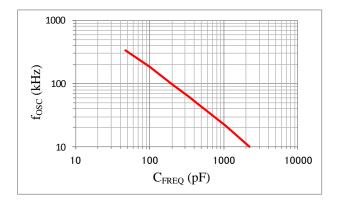


Figure 4-1. Switching Frequency,  $f_{OSC}$ , vs. FREQ Pin Capacitor,  $C_{FREQ}$ 

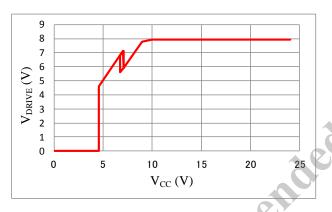


Figure 4-3. DRV Pin Voltage, V<sub>DRIVE</sub>, vs. VCC Pin Voltage, V<sub>CC</sub>

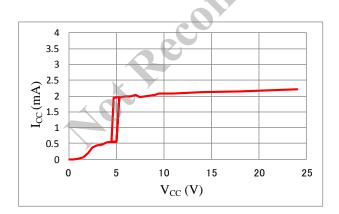


Figure 4-5. VCC Pin Current,  $I_{CC}$ , vs. VCC Pin Voltage , $V_{CC}$ 

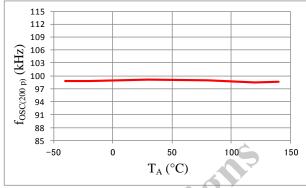


Figure 4-2. Switching Frequency (FREQ = 200 pF) Temperature Characteristics

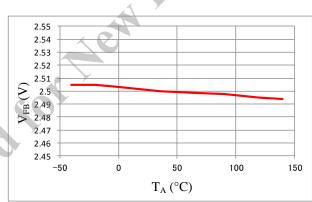
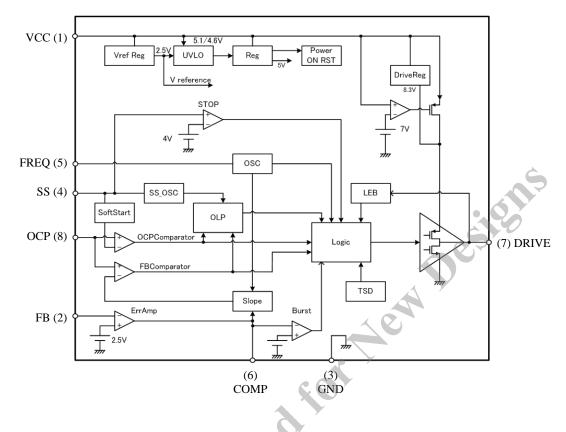
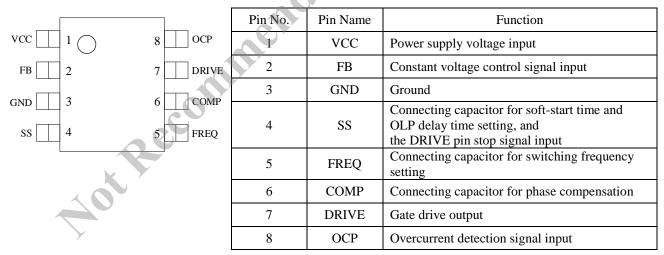


Figure 4-4. Feedback Voltage, V<sub>FB</sub>, Temperature Characteristics

# 5. Block Diagram



# 6. Pin Configuration and Definitions



6

# 7. Typical Application

In applications having a power supply specified such that the drain pin of external power MOSFET has large transient surge voltages, a clamp snubber circuit of a capacitor-resistor-diode (C2, R2, and D1) combination should be added on the primary winding P, or a damper snubber circuit of a capacitor or a resistor-capacitor (C3 and R3) combination should be added between the drain pin and the source pin.

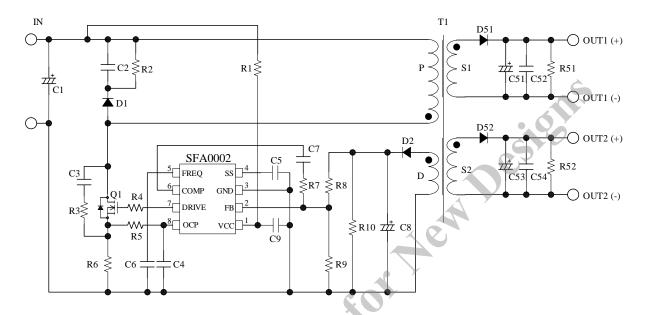


Figure 7-1. Flyback Step-up/ Step-down Converter (Primary-side Detection)

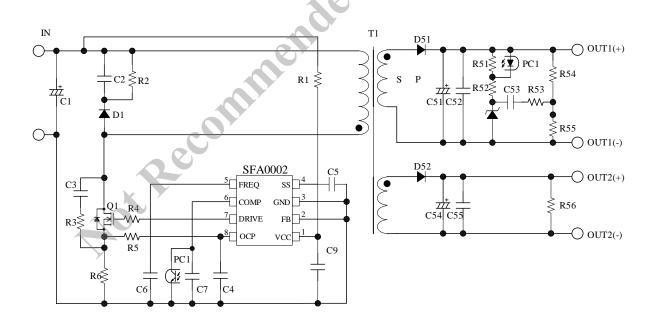
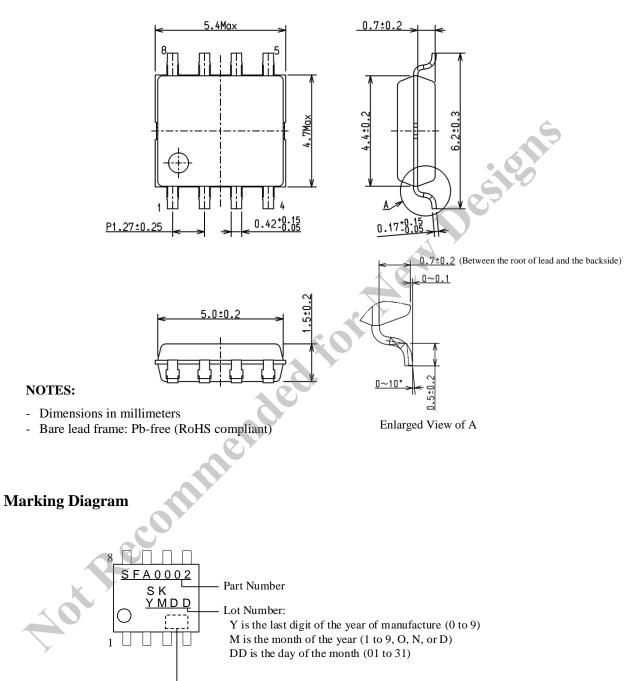


Figure 7-2. Flyback Step-up/ Step-down Converter (Secondary-side Detection)

# 8. Physical Dimensions

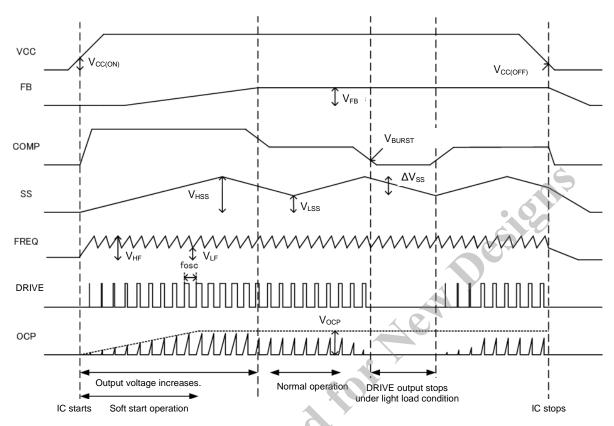
• SOP8

9.



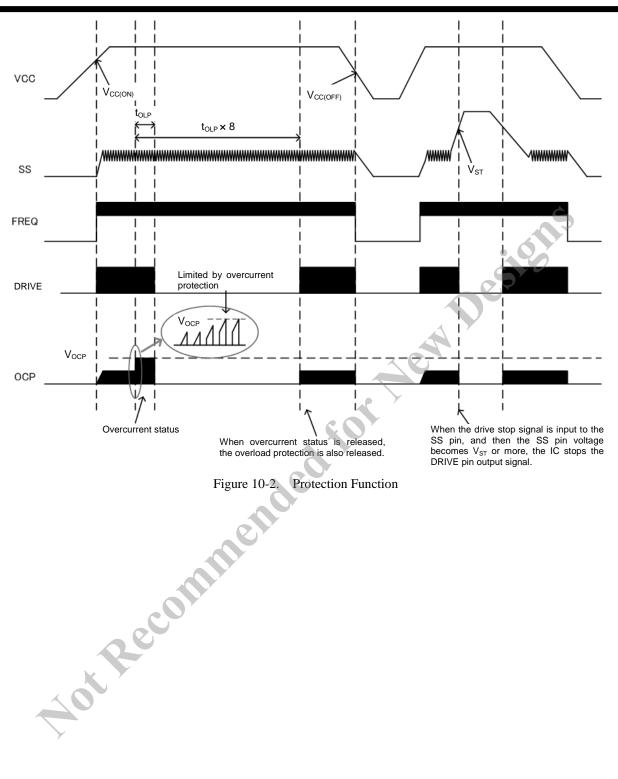
- Control Number

# 10. Timing Chart



When the COMP pin voltage decreases to  $V_{\text{BURST}}$  or less, the IC operation becomes into burst oscillation mode. The on-time and the intermittent cycle depend on the specification of typical application circuit.

Figure 10-1. Normal Operation



# 11. Operational Description

Unless otherwise specified, the characteristics values are shown in typical value. Current polarities are defined as follows: current going into the IC (sinking) is positive current (+); current coming out of the IC (sourcing) is negative current (-).

## **11.1. Pin Descriptions**

## 11.1.1. VCC

The VCC pin is the power input pin of the IC.

When the VCC pin voltage fluctuates greatly, the IC may malfunction. When the impedance of power supply line is high, it is required to add resistors and capacitors to the VCC pin in order to suppress the VCC pin voltage fluctuation.

### 11.1.2. FB

The FB pin is the input of the output voltage of a feedback signal. The IC controls the FB pin voltage to  $V_{FB} = 2.50$  V (see Section 11.4).

# 11.1.3. GND

The GND pin is the IC control ground pin. Since the fluctuation of the ground pin potential may cause the IC malfunction, the control ground trace should be separated from power ground and connected to the GND pin as short as possible. Please pay attention to design of the control ground trace to avoid the effect from the high frequency current line.

#### 11.1.4. SS

The SS pin has three functions as follows:

- Setting the soft start time (see Section 11.3)
- Stopping the drive (see Section 11.7)
- Setting the OLP (Over Load Protection) delay time (see Section 11.9)

The capacitor,  $C_{SS}$ , for setting the soft start time and the OLP delay time is connected to the SS pin. These both functions should be taken into account in setting the value of  $C_{SS}$ .

In normal operation, the waveform of CSS pin voltage is triangular. The SS pin charges the  $C_{SS}$  by  $I_{SRC(SS)} = -15$  µA and discharges the  $C_{SS}$  by  $I_{SNK(SS)} = 17$  µA when the SS pin voltage reaches  $V_{HSS} = 2.0$  V. The SS pin starts to charge again when the SS pin voltage decreases to  $V_{LSS} = 1.0$  V.

# 11.1.5. FREQ

The FREQ pin is connected to the capacitor,  $C_{FREQ}$ , for setting the oscillation frequency of the DRV pin output. For the setting of oscillation frequency, see Section 11.6.

#### 11.1.6. COMP

The COMP pin is the output pin of an internal error amplifier. The capacitor for phase compensation is connected to the COMP pin. The capacitance is set according to the actual operation.

When the secondary output voltage is controlled using an optocoupler, an optocoupler is connected to the COMP pin as shown in Figure 7-2.

### 11.1.7. DRV

The gate of the power MOSFET is connected to the DRV pin. The power of the DRV pin is supplied by the VCC pin via the internal regulator. The relation between the VCC pin voltage and the DRV pin voltage is shown in Figure 11-1. The DRV pin voltage is clamped at  $V_{DRIVE} = 8.3$  V. The internal regulator is switched by VCC pin voltage of around 7 V and suppresses the drive voltage drop at the VCC pin voltage drop.

The source potential of the power MOSFET is increased by about 0.5 V due to a drain current detection resistor. Therefore, it is required to select the power MOSFET with the gate threshold voltage that is lower enough than the minimum drive voltage, 4 V (min.).

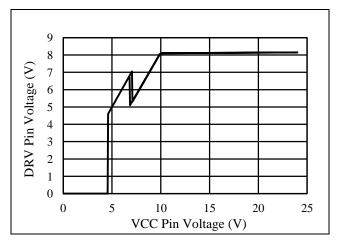


Figure 11-1. VCC Pin Voltage vs. DRV Pin Voltage

## 11.1.8. OCP

The OCP pin is the detection pin of the drain current of the power MOSFET. The current detection resistor,  $R_{OCP}$ , is connected between the source and GND of the power MOSFET, and the voltage is input to the OCP pin. The drain current value input to the OCP pin is used for the output voltage control (see Section 11.4) and the overcurrent protection.

For the setting of overcurrent detection resistor, see Section 11.8.

# 11.2. IC Startup

Applying a voltage to the VCC pin starts the internal regulator. The regulator is a highly accurate power supply of 2.5 V  $\pm$  2%.

When the VCC pin voltage reaches the Operation Start Voltage,  $V_{CC(ON)} = 5.1$  V, or higher, the power supply in the IC turns on and starts the operation. When the VCC pin voltage decreases to be the Operation Stop Voltage,  $V_{CC(OFF)} = 4.6$  V, or lower, the power supply in the IC turns off and stops the operation.

## 11.3. Soft Start Function

The IC operates by soft start in the power supply startup. This reduces the voltage and current stress of the power MOSFET and the secondary rectifier diode.

The soft start period is set by the capacitor,  $C_{SS}$ , connected to the SS pin. When the VCC pin voltage is  $V_{CC(ON)}$  or higher after the power is applied, the IC starts the operation; and the  $C_{SS}$  is charged by the SS Pin Source Current,  $I_{SRC(SS)} = -15 \ \mu A$ .

When the power is supplied, the SS pin voltage starts increasing. The OCP threshold voltage also increases proportional to the SS pin voltage until the SS pin voltage reaches  $V_{\rm HSS}$  = 2.0 V. Thus the drain current gradually increases in this period. When once the SS pin voltage reaches the  $V_{\rm HSS}$ , the OCP threshold voltage is fixed at  $V_{\rm OCP}$  = 0.50 V.

The approximate time of soft start operation,  $t_{ss}$ , is calculated by the following equation.

$$t_{SS}(s) = V_{HSS} \times \frac{C_{SS}}{|I_{SRC(SS)}|}$$
$$= 2.0 \text{ V} \times \frac{C_{SS}(\mu F)}{|-15 \ \mu A|} \tag{1}$$

The  $C_{SS}$  value should be set with the delay time of OLP,  $t_{OLP}$ , taken into account. If the  $C_{SS}$  value is too small, the overload protection is activated in the startup; and the startup failure may be caused.

The recommended  $C_{SS}$  value is 0.01  $\mu$ F to 0.47  $\mu$ F, and should be determined by confirming the actual operation.

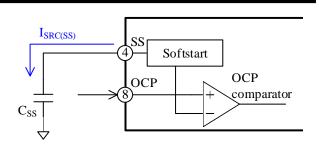
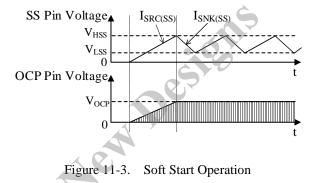


Figure 11-2. SS Pin Peripheral Circuit



# 11.4. Constant Voltage Control

The output voltage control of switching power supply uses the current-mode control method that provides the high speed response and stable operation. The IC has the error amplifier between the FB pin and the COMP pin, and controls the FB pin voltage to  $V_{FB} = 2.50$  V.

Without an optocoupler, the secondary output voltage is controlled by detecting the voltage coupled by the secondary output and the transformer in the primary side, using the auxiliary winding, D, as shown in Figure 11-4. The relation between the smoothing voltage,  $V_D$ , and the secondary output voltage,  $V_{OUT}$ , is determined by the ratio of the auxiliary winding turns,  $N_D$ , and the secondary winding turns,  $N_S$ , as shown in Equation (2).

$$V_{OUT} = \frac{N_S}{N_D} \times V_D$$
(2)

 $V_D$  is divided by resistors. The divided voltage is input to the FB pin. The IC controls the FB pin voltage to  $V_{FB} = 2.50$  V. Thus, the smoothing voltage,  $V_D$ , is calculated by the following equation.

$$V_{\rm D} = \frac{(R8 + R9)}{R9} \times V_{\rm FB} \tag{3}$$

The secondary output voltage,  $V_{OUT}$ , is calculated by the following equation.

$$V_{OUT} = \frac{N_S}{N_D} \times \frac{(R8 + R9)}{R9} \times V_{FB}$$
(4)

The actual  $V_{OUT}$  and the calculated value in Equation (4) do not match because of the leakage inductance between the secondary-side winding and the auxiliary winding, and the difference of the forward voltage,  $V_F$ , between the secondary rectifier diode, D51, and the auxiliary winding diode, D2. Therefore, R8 and R9 must be adjusted by confirming the actual operation.

Where  $N_D = N_S$  and  $V_{OUT} = V_D$ , the accuracy of the secondary output voltage is improved by using the same diode products for D51 and D2.

When there is a big difference of power dissipation between the auxiliary winding and the secondary side, the load regulation is degraded due to the leakage inductance of a transformer. In this case, the dummy resistor, R10, is connected across the auxiliary winding. The value of R10 is adjusted by confirming the actual operation since it differs depending on the power supply specification.

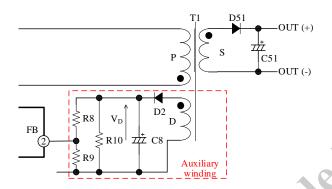


Figure 11-4. Detection by Auxiliary Winding

The voltage control operation in light/heavy load is as follows: (see Figure 11-5)

#### • Light Load Conditions

When the auxiliary winding voltage,  $V_D$ , and the FB pin voltage increase according to the output voltage rise, the COMP pin voltage decreases.

The IC generates the target value of the FB comparator by adding the slope compensation signal to the COMP pin voltage. The IC controls the DRV output duty cycle by comparing the peak of the target value and the OCP pin voltage (the drain current of the power MOSFET detected by detection resistor).

When the COMP pin voltage decreases, the target value of the FB comparator drops. As a result, the drain peak current of the power MOSFET decreases to suppress the output voltage rise.

#### • Heavy Load Conditions

In this case, contrary to the operation describe above, the target voltage of FB comparator increases. As a result, the drain peak current also increases to suppress the output voltage drop.

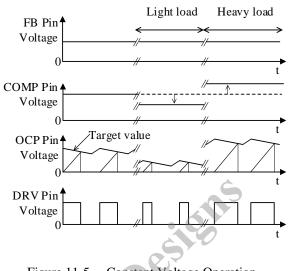


Figure 11-5. Constant Voltage Operation

### 11.5. Burst Function in Light Load

When the output voltage of the power supply decreases, the on-time of DRV pin shortens due to the COMP pin voltage reduction. As a result, the output voltage is controlled to be constant. However, the on-time of DRV pin cannot be shorter than the Minimum On-time,  $t_{ON(MIN)}$ . Therefore, the operation of the IC is automatically switched to the burst oscillation operation (intermittent oscillation) in light load.

When the COMP pin voltage decreases to Burst Operation Threshold Voltage,  $V_{BURST} = 0.18$  V, or lower, the DRV pin output is stopped. Then, the output voltage decreases, resulting in the decrease of FB pin voltage. This increases the COMP pin voltage; and the DRV pin oscillates again. As just described, the burst oscillation operation of the DRV pin is repeated in light load. The following factors depend on the application circuit and power supply specification.

- the burst oscillation frequency and on-time in burst oscillation operation
- the stop period of DRV pin

### 11.6. Oscillation Frequency Setting

The oscillation frequency of the DRV pin output is set by the capacitor,  $C_{FREQ}$ , connected to the FREQ pin (see Figure 11-6).

The waveform of the FREQ pin voltage becomes triangular due to the charge/discharge of  $C_{FREQ}$ .  $C_{FREQ}$  is charged by  $I_{SRC(FREQ)} = -30 \ \mu A$  as shown in Figure 11-7. When the FREQ pin voltage reaches  $V_{HF} = 1.0 \ V$ ,  $C_{FREQ}$  is discharged by  $I_{SNK(FREQ)} = 85 \ \mu A$ . When the FREQ pin voltage decreases to  $V_{LF} = 1.0 \ V$ ,  $C_{FREQ}$  is charged by  $I_{SRC(FREQ)}$  again.

The oscillation frequency of the DRV pin is determined by the frequency of the triangular waveform.

In addition, the maximum duty cycle is controlled by the ratio of charge and discharge. For the setting of oscillation frequency of the DRV pin, see Figure 11-8. Ultimately, the confirmation of actual operation is required.

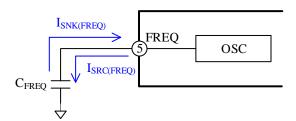


Figure 11-6. FREQ Pin Peripheral Circuit

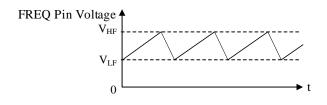


Figure 11-7. FREQ Pin Voltage Waveform

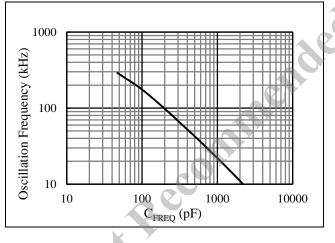


Figure 11-8. Oscillation Frequency vs. C<sub>FREQ</sub> (Reference)

### 11.7. Drive Stop Function

The IC has the drive stop function. When a voltage is externally applied to the SS pin, the function is activated, forcibly fixes the DRV pin output to low level, and stops the oscillation. The input voltage to the SS pin must be set higher than 4.5 V and lower than 9 V.

When the SS pin voltage is lower than Drive Stop Threshold Voltage,  $V_{ST}$ , after the external applied voltage is stopped, the DRV pin starts oscillating again.

### 11.8. Overcurrent Protection (OCP)

The IC has the pulse-by-pulse Overcurrent Protection (OCP).

When the OCP pin voltage exceeds the OCP Threshold Voltage,  $V_{OCP} = 0.50$  V, at every switching cycle, the OCP is activated. When the OCP is activated, it turns off the DRV pin output to turn off the power MOSFET, resulting in suppressing the peak of drain current.

A high frequency switching current flows to the detection resistor. If the resistor with high internal inductance is used, the malfunctions may be caused. The resistor with low internal inductance and high surge capability must be selected. In addition, when the IC malfunctions due to surges in switching operation, the RC filter is added to the OCP pin.

## • Design Example of Current Detection Resistor

The value of the current detection resistor,  $R_{OCP}$ , is set according to the following calculation example in discontinuous operation as a reference. Since the  $R_{OCP}$ and the calculation example do not match in continuous operation, it is required to ultimately adjust by confirming the actual operation.

The peak drain current,  $I_{PEAK}$ , in discontinuous operation is calculated by the following equation.

$$P_{\text{PEAK}} = \frac{2 \times P_{\text{OUT}}}{n \times V_{\text{IN}} \times D}$$
(5)

Where:

 $\begin{array}{l} V_{IN} \text{ is input voltage,} \\ P_{OUT} \text{ is output power,} \\ \eta \text{ is efficiency and} \\ D \text{ is duty cycle of the power MOSFET.} \end{array}$ 

The relation between the power, P, and the drain current,  $I_D$ , is shown in the following equation.

$$P = \frac{1}{2} \times L \times I_D^2$$
(6)

The drain current is proportional to  $\sqrt{P}$ . If the OCP is designed to operate at 130% of the rated load (the maximum output power at the minimum input voltage), the peak of drain current at the OCP operation point is about 114% ( $\sqrt{130\%}$ ) of I<sub>PEAK</sub> at the rated load.

The current detection resistance,  $R_{OCP}$ , is calculated by the following equation.

$$R_{OCP} = \frac{V_{OCP} \times \eta \times V_{IN(MIN)} \times D_{(MAX)}}{114\% \times 2 \times P_{OUT(MAX)}}$$
(7)

Where:

 $D_{(MAX)}$  is the duty cycle at the minimum input voltage,  $V_{IN(MIN)}$  and the maximum output power,  $P_{OUT(MAX)}$ ,  $\eta$  is efficiency, and

 $V_{OCP}$  is the OCP Threshold Voltage (0.50 V).

The waveform of the current flowing through the  $R_{OCP}$  becomes triangular in discontinuous operation. The RMS current is calculated by the following equation.

$$I_{RMS} = I_{PEAK} \times \sqrt{\frac{D_{(MAX)}}{3}}$$
(8)

The power consumption of  $R_{OCP}$  is calculated by the following equation.

$$P_{\rm ROCP} = R_{\rm OCP} \times I_{\rm RMS}^2 \tag{9}$$

# **11.9.** Overload Protection (OLP)

The IC has the Overload Protection (OLP). When the overload state (where the peak of drain current is limited by OCP, or the DRV pin operates in the maximum duty cycle) continues for a certain time,  $t_{OLP}$ , the OLP is activated; and the oscillation of the DRV pin is stopped. This reduces the stress of the power MOSFET and the secondary rectifier diode.

The delay time of the OLP,  $t_{OLP}$ , is determined by the capacitance of  $C_{SS}$  connected to the SS pin. When  $C_{SS}$  is 10 nF,  $t_{OLP}$  becomes 42 ms. In another capacitance, the approximate value of  $t_{OLP}$  can be calculated by the following equation.

$$t_{OLP}(ms) = 42 \text{ ms} \times \frac{C_{SS} (nF)}{10 \text{ nF}}$$

The soft start time in Section 11.3 should be taken into account in setting the  $C_{ss}$  capacitance.

The oscillation stop period of the DRV pin is  $7 \times t_{OLP}$ . The DRV pin repeats oscillation and stop on an  $8 \times t_{OLP}$  cycle until the overload state is dissolved.

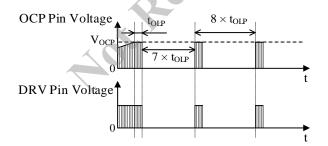


Figure 11-9. Overload Protection Operation

# 11.10. Thermal Shutdown (TSD)

The IC has the Thermal Shutdown (TSD). When the junction temperature of the IC reaches  $T_{JH(TSD)} = 165$  °C, the DRV pin oscillation is stopped. When the junction temperature of the IC decreases to  $T_{JL(TSD)} = 150$  °C or lower due to the oscillation stop, the DRV pin oscillation is restarted.



(10)

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